Structural, electronic, and m agneto-optical properties of $Y \vee O_3$

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Abstract

Optical and m agneto-optical properties of YVO₃ single crystal were studied in FIR, visible, and UV regions. Two structural phase transitions at 75 K and 200 K were observed and established to be of the rst and second order, respectively. The lattice has an orthorhom bic P bnm sym m etry both above 200 K as well as below 75 K, and is found to be dimerized m onoclinic P bl1 in between. We identify YVO₃ as a M ott-H ubbard insulator with the optical gap of 1.6 eV. The electronic excitations in the visible spectrum are determined by three d-bands at 1.8, 2.4, and 3.3 eV, followed by the charge-transfer transitions at about 4 eV. The observed structure is in good agreement with LSDA+U band structure calculations. By using ligand eld considerations, we assigned these bands to the transitions to the ${}^{4}A_{2g}$, ${}^{2}E_{g} + {}^{2}T_{1g}$, and ${}^{2}T_{2g}$ states. The strong temperature dependence of these bands is in agreement with the formation of orbital order. Despite the small net m agnetic m on ent of 0.01 B per vanadium, the K err elect of the order of 0.01 Was observed for all three d-bands in the magnetically ordered phase $T_{Neel} < 116K$. A surprisingly strong enhancement of the K err elect was found below 75 K, reaching a maximum of 0:1. The elect is ascribed to the non-vanishing net orbital magnetic moment.

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I. IN TRODUCTION

The interplay between kinetic energy and Coulomb interaction in strongly correlated electron systems enables small external or internal perturbations to manipulate electronic and magnetic properties of the matter. If, in addition, there is a ground state degeneracy, further interesting phenomena, like an orbital ordering can arise¹.

In yttrium orthovanadate, YVO3, spin and orbital ordering was suggested to be responsible for at least one of the tem perature induced sign reversals of magnetization². In the m agnetically ordered phase, YVO₃ is a canted antiferrom agnet, where a net ferrom agnetic m om ent is form ed by a sm allangle between the antiferrom agnetically (AFM) oriented spins of V³⁺ ions. The transition from the room temperature param agnetic phase to the antiferrom agnetic state occurs at the Neel tem perature $T_N = 116 \text{ K}$. Upon further lowering the tem perature, the magnetic moment gradually changes sign around 90 K. It has been argued that this magnetization reversal is due to the opposing e ects of the D zyaloshinsky-M oriya interaction and the single-ion magnetic anisotropy on the spin canting direction². The magnetization switches sign again around 77 K. At this tem perature the antiferrom agnetic order changes from the high tem perature C type to the low tem perature G type³. A C -type AFM order corresponds to an AFM arrangem ent in planes and a ferrom agnetic arrangem ent between the planes. A G-type AFM order in plies com pletely antiferrom agnetic arrangement, both within planes and between them . Ren et. al.² argued that along with the spin order there is an orbital order on the vanadium sites. A coording to the proposed picture, one of two 3d electrons always occupies the xy orbital, while another electron occupies alternatively either the xz or yz orbital on di erent atom s, thus form ing orbital order. In order to m inim ize the exchange energy a C -type spin order is accompanied by a G -type orbital order and vise versa. The onset tem perature of the orbital order was reported to be much higher than the N celtern perature, $T_{00} = 200 \text{ K}^4$.

The proposed picture of the electronic structure still requires con m ation from, for instance, spectroscopic experiments. The strength of optical transitions involving a charge transfer between orbitals of di erent ions should be highly susceptible to orbital order between the ions. Indeed, one of the aim s of the present research is to study the in uence of orbital ordering on optical transition strengths, and use this technique to study orbital ordering in YVO₃. In this paper we present, amongst others, optical and m agneto-optical

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m easurements of electronic excitations in YVO_3 single crystals. The observed electronic spectra are discussed using ligand eld theory considerations and compared to LDA+U calculations. In addition, magneto-optical Kerr e ect experiments are used to elucidate the spin orientation.

The crystal structure of yttrium orthovanadate YVO₃ was initially reported to have an orthorhom bic P bnm (D_{2h}^{16} in Schoen iess notation) symmetry at all tem peratures^{5,6}. Recent synchrotron measurements^{4,7} report the observation of an additional (401) rejection below 200 K, inconsistent with the P bnm symmetry. The authors concluded⁴ that the crystal structure was most likely $P 2_1 = a$, the highest symmetry subgroup of P bnm. However, the intensity of the P bnm forbidden re ection was four orders of magnitude weaker than to the allowed re ection⁴, which seem ed to make the re nem ent of the X-ray data very di cult. Far infrared (FIR) spectroscopy is a very sensitive tool to study crystal structure variations. M inor atom ic displacements due to a symmetry breaking, which may be di cult to elicit from x-ray analysis, manifest itself through the appearance of new phonon lines in the FIR spectrum. Recently, Ulrich et. al.⁸ proposed that YVO_3 can be subjected to a new sort of Peierls instability, where the new ground state involves a dimerization along the c axis. From the crystallographic and optical points of view this dimerization removes the inversion center, and IR and Ram an active phonons become mixed. The a-axis modes stays nevertheless independent from the b or c axes, if the dimerization a ects only the c axis. We use the FIR vibrational spectroscopy to follow tem perature induced variations of the phonon spectrum and to re ne the crystal structure of YVO $_3$.

II. EXPERIMENTAL DETAILS

Polycrystalline powder of YVO₃ was prepared from YVO₄ powder as starting material. The YVO₄ powder was prepared by a high temperature solid-state reaction from appropriate mixtures of pre-dried Y_2O_3 (99.998 %) and V_2O_5 (99.995 %, metal basis). The oxygen in YVO₄ was reduced by annealing the powder in a low of pure H₂ at 1000 C. The growth process was carried out by the loating zone technique using a four-mirror furnace in a low of Argas⁹. The single-crystalline boule of about 6 mm in diameter and 60 - 70 mm in length was obtained from the growth. The crystallinity of the boule was checked by Laue X-ray di raction. The elemental composition of the crystal was checked by the electron probe

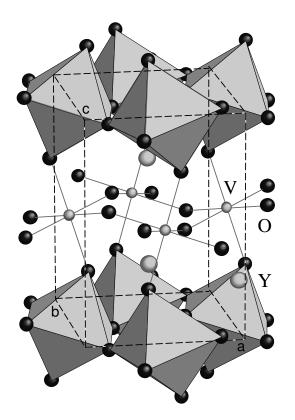


FIG.1: P bnm orthorhom bic crystal structure of YVO $_3$.

m icro analyzer (EPM A) and the results showed that the molar ratios were given by Y ≤ 0 = 1.00:1.00:3.02. A separate check of the composition using the chem ical analysis method showed that the cation ratio of Y over V was 1.00 0.01 and that the oxygen stoichiom etry was 3.03 0.02. Both results were in good agreement.

The dielectric function for near-infrared, visible, and ultra-violent spectral ranges was obtained directly by using the ellipsom etry technique. Because ellipsom etric measurements are very sensitive to contamination of the surface, we used an ultra-high vacuum cryostat with a residual pressure less than 10 8 mbar. The cryostat was specially designed to minimize the movements of the sample due to the thermal expansion of the cold nger. The spectra were measured with a VA SE 32 ellipsom eter from J.A.W oollam Co., Inc., covering a spectral range from 6000 cm⁻¹ through 36000 cm⁻¹ (0.75-4.5 eV).

Far-infrared and mid-infrared re ectivity spectra were measured by Fourier Transform Infrared re ection spectroscopy using a Bruker IFS-113v. The intensity of the re ected light from the sample was referenced to that from a gold mirror for every measured optical surface at each polarization. The sample was mounted on the cold nger of a helium ow cryostat,

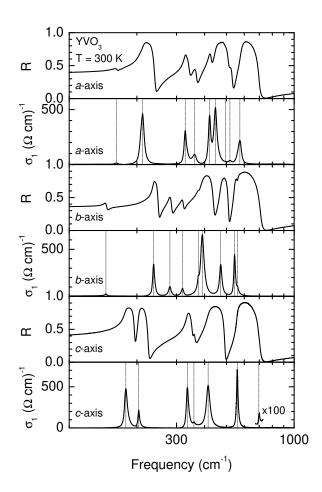


FIG. 2: The room temperature re ectivity and corresponding optical conductivity for the three crystallographic directions. D ashed lines indicate position of the phonon m odes. There are 9, 9, and 7 m odes for the a, b, and c axes, respectively, in agreement with the P bnm symmetry.

whose temperature was varied from 300 K down to 4.2 K.K ram ers-K ronig transform ation was used to calculate the dielectric function and optical conductivity from the re ectivity data in the infrared region. For these calculations we extrapolated the re ectivity below 50 cm⁻¹ with a pure ionic insulator response. For the high frequency extrapolation we used the re ectivity calculated from the ellipsom etric data.

The magneto-optical properties were measured using a home-built Kerr spectrom eter. We used the electro-optical modulation technique, similar to [10], to obtain simultaneously the Kerr rotation and ellipticity induced by the sample. The combination of Xenon arc lamp, windows, Sidetector, and other optical components limited our spectral range to the band from 350 nm through 800 nm (1.55-3.5 eV).

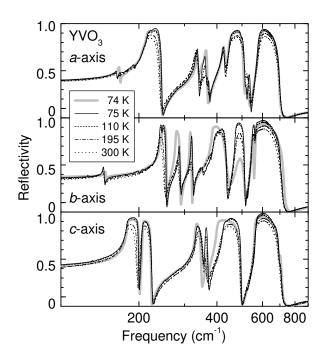


FIG. 3: Tem perature dependence of the FIR re ectivity for three polarizations.

III. STRUCTURAL PHASE TRANSITIONS

The orthorhom bic P bnm crystal structure of YVO₃ is shown in Fig. 1. It can be considered as a distorted perovskite structure. When compared to the perovskite unit cell, the orthorhom bic a and b axes lay along the diagonals of the perovskite unit cell and the corresponding translational vectors are approximately $p_{\overline{2}}$ times longer. The c-axis dimension of the orthorhom bic unit cell is twice as large. The YVO₃ unit cell contains thus four formula units. Vanadium ions have an octahedral surrounding. The octahedrons are distorted, rotated and tilted with respect to each other, as illustrated in Fig. 1.

In the present work we use optically active phonons to track changes in the crystal sym – m etry. As yttrium orthovanadate is an insulating compound, its optical response in the far-infrared (FIR) region is determined purely by lattice vibrations. In Fig. 2 the room temperature re ectivity for all three polarizations is shown together with the optical conductivity. As can be seen, there are 9, 9, and 7 optically active modes respectively for the a, b, and c axes. The positions of the TO phonon frequencies are shown by vertical lines and the frequencies are given in Tables I and II. Som e resonances are very weak. For example, them ode of highest frequency for the c axis is hardly visible in the conductivity and appears as a shoulder on the re-ectivity curve. It gains intensity as the tem perature is lowered, and

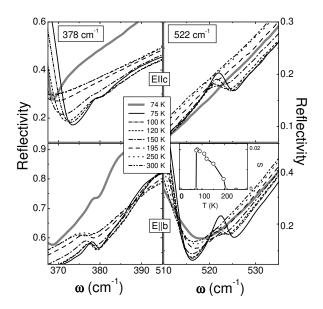


FIG. 4: Left panels: \Leakage" of the b-axis B_{3u} m ode into the c-axis response. Right panels: Appearance of a new previously silent A_u m ode in the b and c responses. Insert: Tem perature dependence of the optical strength of the new m ode.

reaches its maximum in the low temperature orthorhom bic phase. Shown in Fig. 3 is the temperature dependence of the rejectivity for all three polarizations. The number of the phonons stays the same between room temperature and 200 K. Below 200 K a number of additional phonons gradually emerges. We illustrate this by picturing some of the new modes for the b and c axes in Fig. 4. As can be seen from the gure, the intensity of the new modes evolves continuously and monotonically as the temperature decreases, reaching its maximum at 75 K. The optical strengths remain how ever one or two orders of magnitude weaker than that of the original main modes. Below 75 K the new phonons discontinuously disappear. As an example, the temperature dependence of the oscillator strength of the new 522 cm⁻¹ mode is shown in Fig. 4.

To analyze the observed phonon spectra, we apply a group theory analysis. The primitive cell of YVO₃ contains four form ula units, yielding 60 phonon modes in total. In the P bnm lattice the four yttrium atoms and four vanadium atoms occupy equivalent sites 4c and 4b in W ycko notation with the site symmetry C_s^{xz} and C_i , respectively. The 12 oxygen atoms are distributed between two inequivalent sites 4c and 8d with the site symmetry C_s^{xz} and C_i , respectively. Using the general procedure,¹¹ we nd that the phonon normal modes

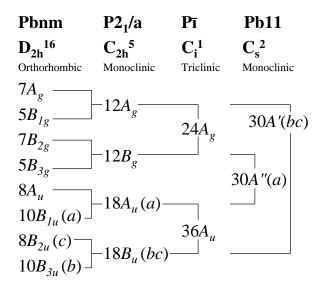


FIG. 5: Transform ations of the phonon irreducible representations due to the descent in lattice symmetry.

transform like 60 irreducible representations

$$= 7A_{q} + 8A_{u} + 5B_{1q} + 10B_{1u} + 7B_{2q} + 8B_{2u} + 5B_{3q} + 10B_{3u}$$

The total representation can be subdivided into three acoustic vibrational modes, B_{1u} + B_{2u} + B_{3u}, 24 R am an active modes, $7A_g + 5B_{1g} + 7B_{2g} + 5B_{3g}$, eight silent A_u modes, and 25 infrared active modes. The infrared vibrations are split into $9B_{1u}$ (E jja), $9B_{3u}$ (E jjb), and $7B_{2u}$ (E jjc) modes with the electric dipole moment aligned along the a, b, and c axes, respectively.

A similar group theory analysis is applied to the lower symmetry structures, P 2_1 =a, P $\overline{1}$, and P bl1, which are sub-groups of the P bnm symmetry. Table III illustrates which symmetry elements are inherited in di erent symmetries. We also show a relation between the widely used notation P bnm, adopted also in this paper, and the standard notation P nm a. The monoclinic P 2_1 =a symmetry is postulated from the X-ray measurements⁷. The triclinic P $\overline{1}$ symmetry, second highest possible symmetry after P 2_1 =a, was proposed by us for the case, when the center of inversion is conserved¹². B oth x-ray⁷ and optical measurements¹² show that the symmetry can not be higher than monoclinic. Recent neutron experiments indicated the possibility of a dimerized state⁸. D in erization displaces them iddle VO₂ plane, see F ig. 1, away from its central position. It removes the inversion center and screw axis from the symmetry operations of P 2_1 =a. The remaining symmetry group includes only a

glide plane b and is referred as P bl1.

As the X-ray measurem ents do not reveal any multiplication of the unit $\operatorname{cell}_{4}^{4}$ the num ber of the atom s in the unit cell is not changed. For monoclinic P 2_1 = a (C $\frac{5}{2h}$) sym metry group one expects 16B u IR active and 2 acoustic modes in the bc plane and 17A u IR and one acoustic modes along the a axis. In case of triclinic P $\overline{1}$ (C $_{i}^{1}$) symmetry, there should be 33A $_{u}$ IR m odes, which can have components along all the three axes. M onoclinic P bl1 (C_s^2) symmetry splits phonons into two irreducible representations 30A⁰ (E jpc) + 30A⁰⁰ (E jp), where R am an and IR modes are mixed. The way how the phonon modes' irreducible representations transform into each other due to the descent in symmetry is depicted in Fig. 5. Both m onoclinic C_{2h}^{5} and triclinic C_{i}^{1} crystal lattices have an inversion center. As a result the \mathbb{R} and R am an m odes do not m ix with each other for these symmetries. In point group C_{2h} , because the b and c axes are not orthogonal any m ore, the corresponding phonons m ix and form the B $_{\rm u}$ representation, 7B $_{2\rm u}$ + 9B $_{3\rm u}$! 16B $_{\rm u}$. The mode A $_{\rm u}$, silent in D $_{2\rm h}^{16}$ symmetry, becom es optically active and together with the B $_{1u}$ m ode gives the A $_u$ representation, 8A $_u$ + 9B_{1u} ! 17A_u. A possible twinning in the b c plane cannot be a reason for leaking the b c phonons to the a axis and vice versa. A Itematively, in the lowest C_i^1 symmetry all the phonons m ix together, as seen in Fig. 5. In the P bl1 sym m etry, R am an A_q m odes become visible in the bc plane and together with the IR B_u phonons form the A⁰ representation, $12A_{g} + 18B_{u}$! $30A^{0}$. Sim ilar, Ram an B_{g} modes can be observed in the a axis response together with IR A_u modes, $12B_q + 18A_u$! $30A^{00}$. An important di erence between P $\overline{1}$ and P bl1 sym m etries is that in P $\overline{1}$ the sam e m odes can be observed in all three polarizations, while in P bl1 a eigenmodes on one side and b and c eigenmodes on the other side remain separate.

At room temperature we observed 9, 9, and 7 phonons for the a, b, and caxes, respectively (see Fig. 2). The TO phonon frequencies !, broadening and optical strength S are presented in Tables I and II. Our observation con rm s the orthorhom bic P bnm symmetry of the crystal lattice at room temperature. At lower temperatures, as far as the crystal structure is concerned, we can conclude from Fig. 4 that the P bnm symmetry is transformed to a lower one below 200 K and it is restored again below 75 K. Evolution of the optical strength of the new phonons with temperature indicates that the transition at 200 K. Surprisingly it is restored again below 75 K. The temperature evolution of the optical strength of the new phonons indicates that the phase transition at 200 K has a second order nature and

that the one at 75 K has a rst order nature. Shown in Table II are the phonon mode frequencies and strengths observed in the caxis spectrum at 75 K. The lines active also in the high tem perature phase are in bold face and assigned to B_{2u} , those appearing only in the interm ediate tem perature phase are labelled by A. Although much more new phonons are seen for all three axes, only the activated c-axis modes, having a counterpart in the other axes, are shown in the table. First, one can see that the original c-axis phonon lines give rise to phonon absorptions along the baxis. The reverse is also valid. The phonons from the baxis Yeak' in the interm ediate phase to the caxis, which is shown in Fig. 4. This agrees with all three symmetries under consideration. However, there is a number of new ly activated absorption peaks (199, 350, and 522 cm 1) in the b and c polarizations, which do not have parents in other polarizations. The fact that these new modes are exactly at the same frequency in both b and c polarizations - as shown in the right panels of F ig. 4 - exclude the possibility of the doubling of the unit cell as their origin. The appearance of new modes is forbidden in the P 2_1 =a symmetry (see also Fig. 5). This observation rules out the P 2_1 =a sym m etry for the interm ediate phase. Because these m odes are not seen in any polarization above 200 K or below 75 K, we can ascribe these phonons either to the previously silent mode A_{11} activated in the P $\overline{1}$ symmetry or to the high temperature R am an modes activated in P bl1 sym m etry. W e did not observe any correlation of phonons between b and c on one side and a on the other side, apart from the modes already present both in a and c polarizations above 200 K, 333 and 420 cm 1 modes in Table II. This could imply that the triclinic distortions are extrem ely sm all, in particular for the a axis. However, the P bl1 sym m etry gives a more natural explanation, as it keeps the a and bc modes apart consistent with the observation. All in all, these facts draw us to the conclusion that the crystal structure of YVO3 in the intermediate phase most likely has a monoclinic P bl1 symmetry. A further test for this conclusion could be a comparison to R am an m easurem ents, when data becom es available.

Finally, we remark on the relation between the electronic and crystal structure changes. From Fig.6 one can see that them ain modes evolve smoothly through the second order phase transition, where the appearance of the orbital order is reported^{4,7}. However, modes change their frequency substantially at the rst order phase transition changes some, where spins and orbitals switch their ordering. The frequency change is found to be particularly strong for the modes around 400 cm⁻¹. From lattice dynamical calculations¹³ for the isostructural

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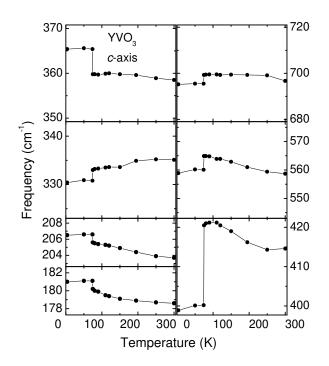


FIG. 6: Tem perature dependence of the TO frequencies for the c-axis B_{2u} phonon modes. For comparison purposes, vertical scale in each square comprises 6% of the central frequency.

com pound LaM nO₃ we conclude that the 400 cm¹ m odes mainly involve vanadium -oxygen bond vibrations. Therefore, it seems that the main structural changes at the rst order transition involve a distortion of the VO₆ octahedra.

IV. ELECTRONIC STRUCTURE

The yttrium Y^{3+} and vanadium V^{3+} ions in YVO_3 both carry the formal charge 3+. Y ttrium has a complete shell, and it can be excluded from the consideration for the electronic transitions. Vanadium has two 3d electrons in the outer shell. We can thus expect two types of optical transitions in the visible range: d d transitions between vanadium ions with the characteristic energy of the M ott-H ubbard gap (M ott-H ubbard (M H) transitions), and the charge-transfer (CT) transitions from the oxygen 2p-band to the free states in the vanadium 3d-band.

Shown in Figs. 7 and 8 are the real and in aginary parts of the YVO_3 dielectric function, " = "⁰ + i"⁰, m easured at various tem peratures. The optical response at low tem peratures is determined by three bands with their maxim a located at 1.8, 2.4, and 3.3 eV, followed

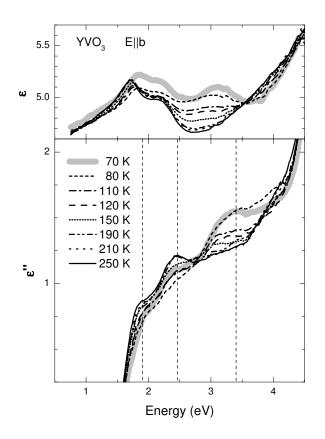


FIG. 7: Tem perature dependence of the real and imaginary part of the b-axis dielectric function for YVO_3 . The vertical lines indicate locations of the band m axim a.

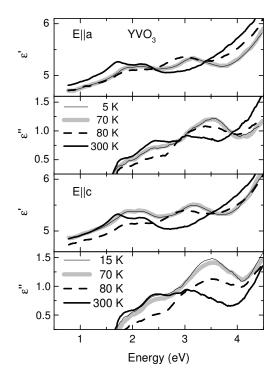


FIG.8: The real and imaginary part of the dielectric function for the a-and c-axes of YVO $_3$.

by a sharp upturn above 4 eV. The optical gap is found at 1.6 eV. It is quite remarkable to observe that the intensity of som e bands, located in the region of a few electron-volts, changes by as much as 50% for temperature variations as low as $k_B T = 26 \text{ meV}$.

Recently M iyasaka et. $al.^{14}$ reported re ectivity m easurements on YVO₃, where the optical conductivity, obtained through the K ram ers-K ronig relations, revealed only two peaks. A loo the tem perature dependence and the reported anisotropy of the conductivity were different. Since "⁰ is approximately ve times smaller than "⁰ in the visible part of the spectrum, the re-ectivity is mainly determined by the real part of ". The d-band structure in "⁰ and "⁰ gives rise to the corresponding re-ectivity variations of only few percent and the tem perature induced changes of the re-ectivity are around 1% or less. This together with the close vicinity of the strong charge transfer transitions place heavy dem ands on the accuracy of the m easurements. A small error can substantially a ect an interpretation of the electronic spectrum . W e used the ellipsom etric technique, which determined "⁰ and "⁰ directly at each particular photon energy and excluded the necessity of reference m easurements. In addition we took special precautions to perform m easurements in ultra-high vacuum in order to avoid condensation on the surface at low tem peratures. W e trust that these measures minimize a possible error.

Let us rst discuss the origin of the bands. Following the general classi cation schem e^{15} , YVO₃ is a M ott-H ubbard insulator. The lowest excitations are $d_i^2 d_j^2 \, ! \, d_i^3 d_j^1$ transitions between di erent vanadium ions, i and j. The uptum above 4 eV is due to charge transfer excitations. This general picture follows from our LSDA+U calculations and agrees with previous room temperature measurem ents^{16,17}. The ne structure of the M H band observed here has not been reported previously and will be discussed using ligand eld theoretical considerations and LSDA+U calculations.

Because the orthorhom bic distortion of the oxygen octahedron is small, we can neglect any on-site d-d excitations. For the same reason we can, considering the energy diagram, restrict ourselves in the rst approximation to the O_h symmetry on the vanadium site. The e_g orbitals can be excluded, because due to the large crystal eld splitting, 10D q, them ixing between e_g and t_{2g} orbitals is expected to be small. Thus, in the strong eld approximation the two d electrons occupy t_{2g} orbitals.

If we take into account the Coulumb interaction, the t_{2g} level is split into ${}^{3}T_{1g}$, ${}^{1}E_{g}$, ${}^{1}T_{2g}$, and ${}^{1}A_{1g}$ levels, as shown in Fig. 9 (a). The ${}^{1}E_{g}$ and ${}^{1}T_{2g}$ levels are degenerate in

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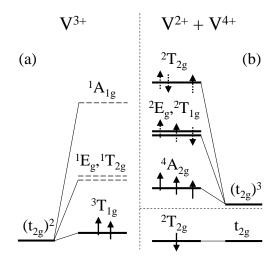


FIG. 9: Energy diagram for (a) the ground state of the vanadium ions and (b) excited states of two vanadium sites.

the O_h symmetry. In the ground state the d electrons occupy the lowest energy S=1 state, ³T_{1g}, in agreement with the Hund's rule. The M H excitations occur from the initial state with two vanadium in the d² state to the nal state with the rst atom in the d¹ (V⁴⁺) and the second in the d³ (V²⁺) states. In the nal state the wave function of the single electron follows obviously only one irreducable representation ²T_{2g}, while the d³ state splits into four levels, ⁴A_{2g}, ²E_g, ²T_{1g}, and ²T_{2g}, with ²E_g and ²T_{1g} again being degenerate. The energy diagram of the nal state is depicted in Fig. 9 (b). The three observed bands in Fig. 7 correspond to transitions to these three energy levels. A coording to the measurements, these bands span the energy range of 1.5 eV from 1.8 eV to 3.3 eV.W ith the crystal eld splitting of 10D q 2 eV, our assumption of a sm all admixture of e_g orbitals is justified.

The picture obtained with the ligand eld theory is in good agreem ent with our LSDA+U calculations. The LSDA+U band structure calculations has been performed in the LM TO calculation schem $e^{18,19}$. Vanadium 3d partial density of states were obtained in the LDA+U calculation with U = 3:4 eV and J = 0:85 eV for the low temperature crystal and m agnetic structure of YVO3. The results are consistent with previous calculations of the electronic structure²⁰. As can be seen from the electron density of states in Fig. 10, the highest occupied states are from a narrow d band, with both electrons in a spin-up state. The AFM ordered neighboring vanadium ion should be accordingly in a spin-down state. The lowest unoccupied band corresponds to the addition of an electron with spin up. This agrees with

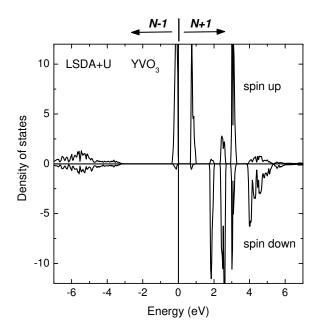


FIG. 10: Vanadium 3d partial density of states for spin-up and spin-down electrons, obtained in local spin-density approximation with the Hubbard potential U taken into account. N 1 and N + 1 correspond to the electron removal and electron addition states, respectively.

the lowest excited ${}^{4}A_{2g}$ state, which indeed puts electrons in the high-spin state S = 3=2. Two consequent excitation bands are formed by transfer of spin-down electrons, again in agreement with the low S = 1=2 spin states in the ${}^{2}E_{g}$, ${}^{2}T_{1g}$, and ${}^{2}T_{2g}$ representations found from the ligand eld theory. Higher electron-addition bands with equal spin-up/spin-down populations have an e_{g} origin. From the energy distribution of the bands in Fig. 10 one can see that YVO_{3} is indeed a M ott-H ubbard insulator¹⁵. The lowest excitations are d d transitions, $d^{2}d^{2}$! $d^{3}d^{1}$. The charge-transfer transitions, d^{2} ! $d^{3}L$ occur at higher energies than the d d transitions.

The tem perature dependence of the optical response of YVO_3 is shown in Figs. 7 and 8. There is only small T-dependence between 70 K and 6 K, as can be seen in Fig. 8, and the corresponding data are further on itted from the consideration. To clarify the tem perature dependence of the M H bands, Fig. 11 shows a dimensional dielectric function for E jb, where the 250 K data are subtracted from the curves in Fig. 7. In order to quantify tem perature variations of the optical strength of the bands, we tted simultaneously the real and imaginary parts. The dimensional dielectric function turned out to be well tted with three gaussians in the imaginary part and with its H ibert transform, D aw son function,

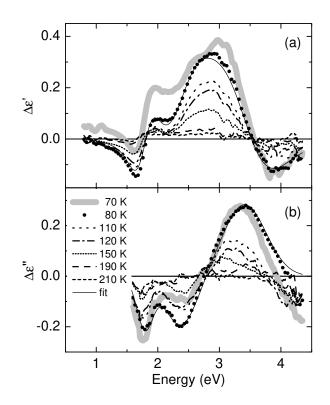


FIG. 11: The dielectric functions from Fig. 7, the real and im aginary parts, with subtracted 250 K data. The t curve shows a simultaneous t to the real and im aginary part for the 80 K data.

in the real part. The tted curves for 80 K are shown along with the experimental data in Fig. 11. The full dielectric function shown in Fig. 7 was also tted in the same way, but an additional fourth gaussian was necessary to account for the CT band. In this way the position of the bands was con rm ed to be temperature independent. However, it was not possible to determ ine accurately the absolute optical strength of the MH bands due to an additional non-gaussian contribution. It was also in possible to determ ine the position of the 3.3 eV band at high temperatures because of its vanishing presence in the spectra. The band positions and optical strengths obtained from the ts are plotted in Fig. 12. The dielectric function reveals m inim al variations between room temperature and the second order structural phase transition at 200 K. Below 200 K a strong growth of the 3.3 eV band is observed, which is accompanied by the decrease of the 1.8 and 2.4 eV bands. The total change of the optical strength of these MH bands remains virtually zero down to the N eel temperature, $T_N = 116$ K. In the magnetically ordered state the 3.3 eV band acquires additional strength. The additional spectral weight transfer should come from higher energies, most probably from the e_q states, as the decrease of the low energy bands

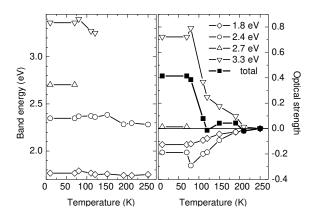


FIG. 12: Tem perature dependence of the bands position (left) and their optical strength together with the total spectral weight of the three bands (right).

cannot account for it. Indeed, the lowest energy state in the $t_{2g}^2 e_g$ con guration is obtained by adding an e_g electron to the ground state ${}^3T_{1g}$. Four irreducible representations, ${}^4T_{1g}$, ${}^4T_{2g}$, ${}^2T_{1g}$, and ${}^2T_{2g}$ can be formed from this con guration, where the latter representation descends also from the t_{2g}^3 con guration. Antiferrom agnetic order favors transitions to the low-spin states and thus gives additional optical strength to the ${}^2T_{2g}$ state.

At the rst order phase transition, the optical strength of the 2.4 and 3.3 eV bands experiences jumps in opposite directions. A dditionally, as can be seen in Fig. 11 (a), a new shoulder emerges at around 2.7 eV. This appears in Fig. 7 as an extended at region, which becomes visible probably due to the narrowing of the 3.3 eV band. However, its optical strength is very small.

The optical spectrum begins to change below the second order phase transition at 200 K. These changes can not be directly related to the lower symmetry as the 3.3 eV band does not disappear in the low temperature orthorhom bic phase. The reason should rather come from some electronic correlations and associated distortions of the VO₆ octahedrons. Ren et al.² suggested that the spin order in YVO₃ is accompanied by an orbital order. The orbital order is reported to appear below the 200 K phase transition^{4,7}. In the proposed picture for the orbital ordering, the xy-orbitals are always occupied by one of the two d electrons, while the occupation of the xz and yz orbitals alternates in an AFM order. The orbital order was found to be di erent above and below 77 K in agreement with the di erent m agnetic order. A coording to Ren et al.², there is a C-type m agnetic and G-type orbital order above 77 K, and alternatively G-type m agnetic and C-type orbital order below 77 K.

We now turn to the discussion of how orbital and magnetic ordering in uences the optical conductivity. We consider a model, where the optical conductivity is proportional to the electron transition probability between two neighboring vanadium sites. There are in total nine independent eigenfunctions in the ${}^{3}T_{1q}$ representation. At room temperature the electron transition probability can be calculated by averaging over arbitrary orientations of spin and orbits on two ions, i.e. by averaging over all linear combinations of these 9 wave functions. M agnetic or orbital order limits the choice of the initial wave functions. At lower tem peratures we can expect that the electron transition from the S=1 state on the rst ion to the S=3/2 state on the other ion becomes less probable due to the antiferrom agnetic order. Thus, the intensity of the lowest band should decrease. As can be seen from Fig. 7 and Fig. 11, the optical strength of the lowest band indeed decreases together with tem perature. By using a more rigorous analysis of the transition probabilities, we can evaluate if a particular order is consistent with the observed tem perature dependence for "(!). In this analysis we neglect the tilting of octahedrons, and assume that the transition integrals between d-orbitals on the neighbor vanadium ions are the same for all directions and for all d orbitals. The conductivity is assumed to be determined by the probabilities to create a pair consisting of an occupied orbitation one site and an empty orbitation the neighboring site, with the constraint that the transition is allowed. The intersite d d transitions are m ediated by the porbitals of the oxygen ions between the vanadium sites. At room tem perature all ${}^{3}T_{1q}$ states are occupied random ly. At lower tem peratures we used the magnetic and orbital order, suggested above². If we assume the transition integral from completely occupied to completely empty orbital as unity, then the transition probabilities at room tem perature are found to be 0.49, 0.84, and 0.44 for the ${}^{4}A_{2q}$, ${}^{2}E_{q}$ + ${}^{2}T_{1q}$, and ${}^{2}T_{2q}$ nal states, respectively. We also calculated the transition probabilities for AFM spin order and for AFM spin order accompanied by the aforem entioned orbital order (see Table IV). Both simple AFM-SO and AFM-SO+OO lead to a decrease of the lowest band and an increase of the intensity of the highest band, consistent with the observations.

However, none of the considered orderings gives the correct sign for the intensity change for the middle band, i.e. a decrease of strength with decreasing temperature. Moreover, we found that no combination of completely polarized states ($S_z = 1$) can give the desired intensity decrease for the ${}^{2}E_{g} + {}^{2}T_{1g}$ band. The same conclusions hold if the on-site symmetry is lowered to tetragonal. If some addition of the $S_z = 0$ initial wave function is allowed, as

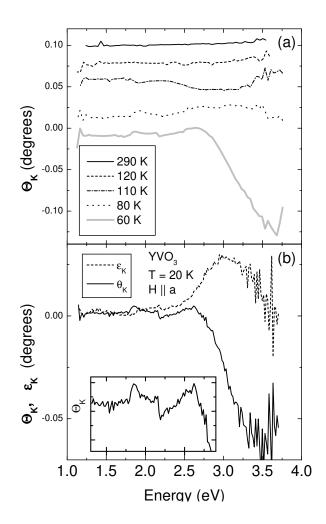


FIG.13: (a) Tem perature dependence of the Kerr rotation measured in the polar geometry with H jja. (b) The Kerr rotation $_{\rm K}$ together with the Kerr ellipticity " $_{\rm K}$ in the low tem perature phase. (Insert) Enlarged view of the resonances at 1.8 and 2.2 eV.

suggested by neutron m easurem ents⁴, a whole num ber of possible orbitally ordered structures becom es allowed. A lthough di erent orbital orderings can indeed explain the observed intensity changes, it is not possible to give a preference to a particular order²¹.

V. MAGNETO-OPTICAL KERR EFFECT

The energy diagram shown in Fig. 9 was derived assuming a local cubic symmetry on the vanadium site. In reality, one axis of the octahedron is dierent from the other two. This tetragonal type distortion additionally splits the multiplet structure, which partially lifts the degeneracy of the ground and excited states. On top of that, a spin-orbital coupling provides segregation of the states by the quantum number $M_{\rm J}$. The latter gives rise to the magneto-optical Kerr e ect (MOKE). Tem perature dependence of the Kerr rotation spectrum _K (E) is shown in Fig. 13. The curves are shifted for clarity. The measurem ents were perform ed in the polar geometry at nearly norm al angle of incidence, with magnetic eld of 0.1-0.2 T parallel to the a axis, H ja. In the other eld orientations, the magnetic m om ent was too sm all for the K err rotation to be detected. No rotation of the polarization plane was observed above the Neel tem perature within our experim ental error. Below the Neel tem perature but above the rst order phase transition, only a weak structure of the order of _K 0.01 can be seen. Below 75 K a remarkable peak as large as $_{\rm K}$ = 0.1 is observed. In total, there are three resonance structures. Enlarged in the insert of Fig. 13 are two surprisingly narrow dispersion type resonances at 1.8 and 2.2 eV that have positions approxim ately corresponding to the onset of the two st M H bands. Their intensity, though rather sm all 0:01, is well reproduced on di erent sam ples. The third broad peak appears to have maximum at 3.5 eV, which is also con med by the zero crossing of the Kerr ellipticity " $_{\rm K}$ (E). This band lies below the charge-transfer onset and corresponds to the d transitions. The maximum rotation in this band amounts to d 0:1. Such a large magneto-opticale ect seems to be quite surprising, because from the electrodynamics point of view the time-reversal symmetry, although broken on the microscopic scale, is usually restored on the macroscopic scale in antiferrom agnetic compounds. If this indeed were the case in YVO3, the Kerr rotation would mainly result from the small 02 spin canting and would be as minuscule as the net magnetic moment is. For comparison, the saturation m agnetic m om ent in N i is 0.61 $_{\rm B}$ per atom, i.e. approxim ately 60 tim es larger that the net moment of 0.01 Bohrmagneton per vanadium atom in YVO3. Still the Kerr rotation in Ni is quite comparable to those of the low temperature phase of YVO₃ and lies between 0:1 and 0.2 in the visible range.

Antiferrom agnetic compounds can have large magneto-optical e ects, as was shown recently^{22,23}, if the local spin and orbital magnetic moments are not collinear. In particular, an orbital magnetic moment does not vanish in transition-metal perovskites with the P bnm structure due to the tilting of the octahedra²⁴. We can not non-vanishing ferrom agnetic components of the net orbital magnetic moment M_L from symmetry considerations, following the guideline and notations from Ref. 24. There are four inequivalent vanadium sites i = 1;2;3;4 in the YVO₃ unit cell. These sites can be generated by four symmetry

transform ations, unity operation E, and three screw axes, S_{2x} with the shift $(\frac{1}{2},0,0)$ and coordinates $x,\frac{1}{4},0$; $S_{2y}(0,\frac{1}{2},0)$, $\frac{1}{4},y,\frac{1}{4}$; and $S_{2z}(0,0,\frac{1}{2})$, 0,0,z. Here x,y, and z are parallel to the crystallographic axes a, b, and c, respectively. The local relation between the orbital magnetic moment M $_{L}^{i}$ and spin magnetization direction $e = (\cos \sin i)$; sin sin; cos) on each vanadium site i can generally be written as M $_{L}^{i} = L^{i} e$, where the matrix L^{i} determines the orbital magnetic moment matrix L^{i} determines the orbital magnetic moment matrix L^{i} to obtain averaged matrices $L = \frac{P}{\frac{4}{i=1}}L^{i}$ for the C- and G-type spin ordering, respectively:

$$L^{C} = 4 \begin{bmatrix} 0 & 1 & 0 & 1 \\ B & 0 & L_{xy}^{1} & 0 \\ B & L_{yx}^{1} & 0 & 0 \\ 0 & 0 & 0 \end{bmatrix} L^{G} = 4 \begin{bmatrix} 0 & 0 & L_{xz}^{1} \\ B & 0 & 0 & 0 \\ B & 0 & 0 & 0 \end{bmatrix} L_{xz}^{1} = 0$$

The corresponding net orbital magnetic moments are

C : M
$$_{\rm L}^{\rm C}$$
 = 4 (L $_{\rm xy}^{\rm 1}$ sin sin ;L $_{\rm xy}^{\rm 1}$ sin cos ;0);
G : M $_{\rm L}^{\rm G}$ = 4 (L $_{\rm xz}^{\rm 1}$ cos ;0;L $_{\rm zx}^{\rm 1}$ sin cos):

The orbitalm agneticm om ent M_L has the same symmetry as the gyration vector g^{25} , which determ ines the antisymmetric part of the dielectric tensor, $\mathbf{w}^a = \mathbf{i} = \mathbf{g}$, which is responsible for mageto-optical e ects²⁶. Here e is the unit antisymmetric tensor. In the polar measurement geometry discussed here, components of the vector g and correspondingly components of M_L de ne the orientation of magnetic eld H, at which the observation of Kerr e ect is possible.

For the G-type spin order, the structure of M $_{L}^{G}$ suggests that the polar K err e ect can exist for H ja, if spins are parallel to the c axis, and for H jc, if spins are aligned along the a axis. If the spins are along the b axis, M $_{L}^{G}$ and the corresponding K err e ect are zero. This does not exclude the possibility for the second, weaker, type of K err e ect, which is directly related to the spin canting. It should be emphasized here that the K err rotation due to the orbital m agnetic m on ents can exist even if spins are exactly antiferrom agnetically aligned²⁴. O ur observation of the substantial m agneto-optical e ect only for H jja shows that spins in the low tem perature phase of YVO₃ are aligned along the c axis. This agrees with the neutron scattering m easurem ents⁴. The weak structure at 1.8 and 2.2 eV is most probably the spin canting e ect.

The C-type spin order as seen from the M $_{\rm L}^{\rm C}$ angular dependence allows a magneto-optical activity, only if spins are aligned in the ab plane. The smallm agnitude of the experimentally observed M OKE above 80 K compared to the low temperature phase suggests that the spins are aligned along the c axis. In this case, M $_{\rm L}^{\rm C}$ is zero for any orientation of H, and K err e ect substantially decreases, in agreement with the our experimental observations. This result contradicts the neutron data, where a substantial spin component along the b axis is observed⁴. This, however, can relect another in portant property of YVO₃. As it was shown in R ef. 27, the G-type antiferrom agnetic orbital order in the form proposed by R en et. al.² suppresses the orbital magnetic m om ent. This can be the reason, why no substantial K err rotation was observed for the C-type spin order. This conclusion requires that the on-site m agnetic m om ent, but due to a m ixture of S_z = 1 and S_z = 0 ${}^{3}T_{1g}$ states, in agreement with the conclusion obtained in the previous section.

VI. CONCLUSIONS

The analysis of the YVO₃ phonon spectra revealed three di erent phases. The orthorhom – bic P bnm structure exists down to 200 K.At 200 K there is a second order phase transition to a lower symmetry structure. Orthorhom bic P bnm crystal symmetry is restored through a rst order phase transition below 74 K. The most probable structure in the intermediate phase is the monoclinic P bl1, where the VO₆ octahedra form a dimerized chain along the c axis. The triclinic P $\overline{1}$ symmetry cannot how ever be completely excluded.

 YVO_3 is a M ott-H ubbard insulator with the optical gap of 1.6 eV. There are three optical bands with energies 1.8, 2.4, and 3.3 eV. We identify these bands with the inter-vanadium transitions from the ${}^{3}T_{1g}$ ground state to the ${}^{4}A_{2g}$, ${}^{2}E_{g} + {}^{2}T_{1g}$, and ${}^{2}T_{2g}$ states. These d d excitations are followed by the charge-transfer transitions at 4 eV. The band gap structure is in agreement with the LSDA+U calculations. The d bands revealed strong tem – perature dependence. Using a model, which includes only the nearest neighbor transitions, we found that the observed temperature dependence disagrees with the simple antiferrom agnetic spin ordering. This indicates that an orbital order is responsible for the band temperature variations. However, the commonly considered j_{XY} ; $x_{Z} = j_{XY}$; $y_{Z} = j_{YY}$. We observed two types of magneto-optical e ect. Small net magnetic moment due to the uncompensated spin moments induces the weak Kerr rotation of the order of 0:01. The e ect exists in all phases below the magnetic ordering temperature and for all active optical transitions. A strong Kerre ect appears as a consequence of the low crystallographic symmetry and ferrom agnetic ordering of orbital magnetic moments. The Kerr rotation of the order of 0:1 was found in the low temperature phase for the highest d d transition band. It follows from the symmetry considerations that the spin magnetic moment lays along the caxis in both magnetic structures. However, this conclusion for the C-type AFM spin arrangement can be a ected by the accompanying orbital order.

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M ode	Frequency	Sa	Sb	Sc
B _{2u}	180.2			7
A	199		0 : 037	0:008
B _{2u}	205.6		0:006	0 : 78
B _{2u}	333.0	0:19	0:008	2:9
A	350		0 : 67	0:003
B _{2u}	359.8		0:02	0:37
B _{2u}	420.5	1:6	0:076	1:6
A	522		0:024	0:018
B _{2u}	564.9		0:014	12
B _{2u}	699.2			0:002

TABLE II: c-A x is phonons at 75 K \cdot B $_{2u}$ m odes originate from the room tem perature phase. New vibrationalm odes, appearing below 200 K, are designated as A

B _{1u} (a)		B _{3u} (b)			
!, cm 1	, an 1	S _a	!, cm 1	, an 1	Sb
162.2	3:2	0:08	144.3	15 : 5	0 : 73
211.6	8:5	5:4	237.4	5:5	2:0
328.5	9:9	1:6	280.1	8 : 4	0 : 64
359.2	15 : 0	0:56	318.7	7 : 8	0 : 35
420.8	10:4	1:4	374.5	63	0:22
446.8	17:3	2:6	390.7	16 : 5	4:21
494.5	10:0	0:005	471.7	13:3	12
517.5	15 : 5	0:06	543.7	9 : 8	0 : 86
572.4	22 : 6	0:91	559 . 8	17 : 5	021

 ${\tt TABLE}\ {\tt I:TO}\ {\tt phonon}\ {\tt m}\ {\tt odes}\ {\tt for}\ {\tt the}\ {\tt a}\ {\tt and}\ {\tt b}\ {\tt axes}\ {\tt at}\ {\tt room}\ {\tt tem}\ {\tt perature}.$

N	P nm a	P bnm	P 2₁=a	P 1	P b11
	D ¹⁶ _{2h}	D ¹⁶ _{2h}	C ⁵ _{2h}	C _i	C ² _s
(1)	1	1	1	1	1
(2)	$2(0;0;\frac{1}{2})\frac{1}{4};0;z$	$2(\frac{1}{2};0;0) \times ;\frac{1}{4};0$	21	-	_
(3)	$2(0;\frac{1}{2};0)0;y;0$	2(0;0; ¹ / ₂)0;0;z	-	_	_
(4)	$2(\frac{1}{2};0;0) \times; \frac{1}{4}; \frac{1}{4}$	$2(0;\frac{1}{2};0)\frac{1}{4};y;\frac{1}{4}$	-	_	_
(5)	{	{	{	{	_
(6)	ax;y; <u>1</u>	b <u>1</u> ;y;z	b	-	b
(7)	m x; ¹ / ₄ ;z	m x;y; <u>1</u>	-	-	-
(8)	n (0; $\frac{1}{2}$; $\frac{1}{2}$) $\frac{1}{4}$; y; z	$n(\frac{1}{2};0;\frac{1}{2})x;\frac{1}{4};z$	_	-	_

TABLE III:Possible sym m etries and sym m etry operations in the interm ediate phase (75K $\,<\,$ T $\,<\,$ 200K).

TABLE IV : Calculated transition probabilities at room temperature, in the AFM spin ordered (SO) state and in the AFM spin and orbital ordered (SO-00) state.

0 rder	⁴ A _{2g}	$^{2}\mathrm{E}_{g}$ + 2 T _{1g}	$^{2}\mathrm{T}_{2\mathrm{g}}$
Room tem perature	0:49	0:84	0:44
AFM SO	0:30	1:48	0 : 89
AFM SO-OO	0:33	1:67	1:0